#### **PATENT**



Case Docket No. ASMEX.367A Date: October 16, 2003

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s)

Michael A. Todd

Appl. No.

10/074,534

Filed

February 11, 2002

For

PROCESS FOR DEPOSITION OF SEMICONDUCTOR FILMS

Examiner

Shrivinas H. Rao

Group Art Unit:

2814

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

October 16, 2003

## TRANSMITTAL LETTER

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

#### Dear Sir:

Enclosed for filing in the above-identified application are:

- (X) An Information Disclosure Statement.
- A PTO Form 1449 with seven (7) references. (X)
- (X) The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment, to Account No. 11-1410.
- (X) Return prepaid postcard.

Registration No. 39,287

Attorney of Record

Customer No. 20,995

(619) 235-8550

Docket No.: ASMEX.367A

# INFORMATION DISCLOSURE STATEMENT

**Applicant** 

Michael A. Todd

App. No.

10/074,534

Filed

: February 11, 2002

For

PROCESS FOR DEPOSITION OF

SEMICONDUCTOR FILMS

Examiner

Shrivinas H. Rao

Group Art Unit

2814

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Enclosed is form PTO-1449 listing seven (7) references that are also enclosed.

This Information Disclosure Statement is being filed before the receipt of a first Office Action on the merits, and presumably no fee is required in accordance with 37 C.F.R. § 1.97(b)(3). If a first Office Action on the merits was mailed before the mailing date of this Statement, the Commissioner is authorized to charge the fee set forth in 37 C.F.R. § 1.17(p) to Deposit Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated:

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Joseph J. Mallon

Registration No. 39,287

Attorney of Record

Customer No. 20,995

(619) 235-8550

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FORM PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ATTY, DOCKET NO. ASMEX.367A

APPLICATION NO. 10/074,534

INFORMATION DISCLOSURE STATEMENT

**BY APPLICANT** 

APPLICANT Michael A. Todd

(USE SEVERAL SHEETS IF NECESSARY)

FILING DATE **GROUP** February 11, 2002 2814

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
	1.	5,389,398	02/14/95	Suzuki et al.	427	130	
	2.	5,698,771	12/16/97	Shields et al.	73	31.05	
	3.	6,228,181	05/08/01	Yamamoto et al.	148	33.5	
	4.	6,326,311	12/04/01	Ueda et al.	438	694	
	5.	6,455,892	09/24/02	Okuno et al.	257	328	
	6.	6,613,695	09/02/03	Pomarede et al.	438	767	

FOREIGN PATENT DOCUMENTS							
EXAMINER	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
INITIAL			-			YES	NO

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)				
	<ol> <li>Ikoma et al., Growth of Si/3C-SiC/Si(100) hetrostructures by pulsed supersonic free jets, Applied Physics Letters, Volume 75, No. 25, Pp. 3977-3979, December 1999</li> </ol>				

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DATE CONSIDERED